

TECHNICAL DATA
DATASHEET 5435, Rev B

Diode Array

- **Devices Are Serialized**
- **Eight 1N5615 diodes in surface mount package**
- **Die manufactured on qualified JANS line**
- **Built and screened to space level quality (SDA1007SS)**
- **Quality Conformance Inspection (QCI) in accordance with MIL-PRF-38534 is performed on each lot (SDA1007SS)**
- **Add suffix "S" for screening per MIL-PRF-38534, Class H (SDA1007S)**
- **Add suffix "SS" for Space Level Screening per MIL-PRF-38534, Class K (SDA1007SS)**

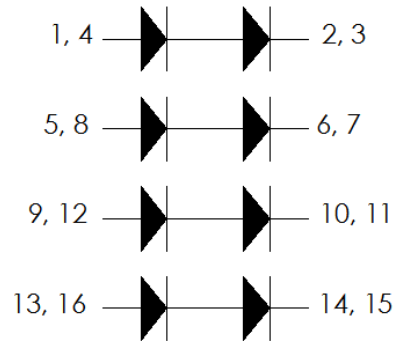
MAX. RATINGS / ELECTRICAL CHARACTERISTICS FOR EACH DIODE PAIR

All rating at are $T_A = 25^{\circ}\text{C}$ unless otherwise specified

RATING	SYMBOL	MAX	UNIT
Peak Inverse Voltage (DC)	PIV	400	V
Average DC Output Current $T_A = 55^{\circ}\text{C}$ $T_A = 100^{\circ}\text{C}$	I_O	1.0 0.75	A
Peak Single Cycle Surge Current ($T_p=8.3\text{ms}$ single half-Sine wave superimposed on rated load)	I_{fsm}	10	A
Max. Operating Junction Temperature	T_J	-55 to +150	$^{\circ}\text{C}$
Max. Operating Ambient Temperature	T_{OP}	-30 to 100	$^{\circ}\text{C}$
Storage Temperature Range	T_{stg}	-65 to +175	$^{\circ}\text{C}$
Maximum forward voltage @3.0A	V_f	3.2	V
Maximum Instantaneous Reverse Current At Rated (PIV)	$T_A = 25^{\circ}\text{C}$ $T_A = 100^{\circ}\text{C}$	0.5 25	μA
Max. Reverse Recovery Time $I_F = 0.5\text{ A}$, $I_R = 1.0\text{A}$, $I_{RR} = 0.25\text{A}$	t_{rr}	150	ns
Thermal Resistance Junction to Case	θ_{JC}	21	$^{\circ}\text{C}/\text{W}$

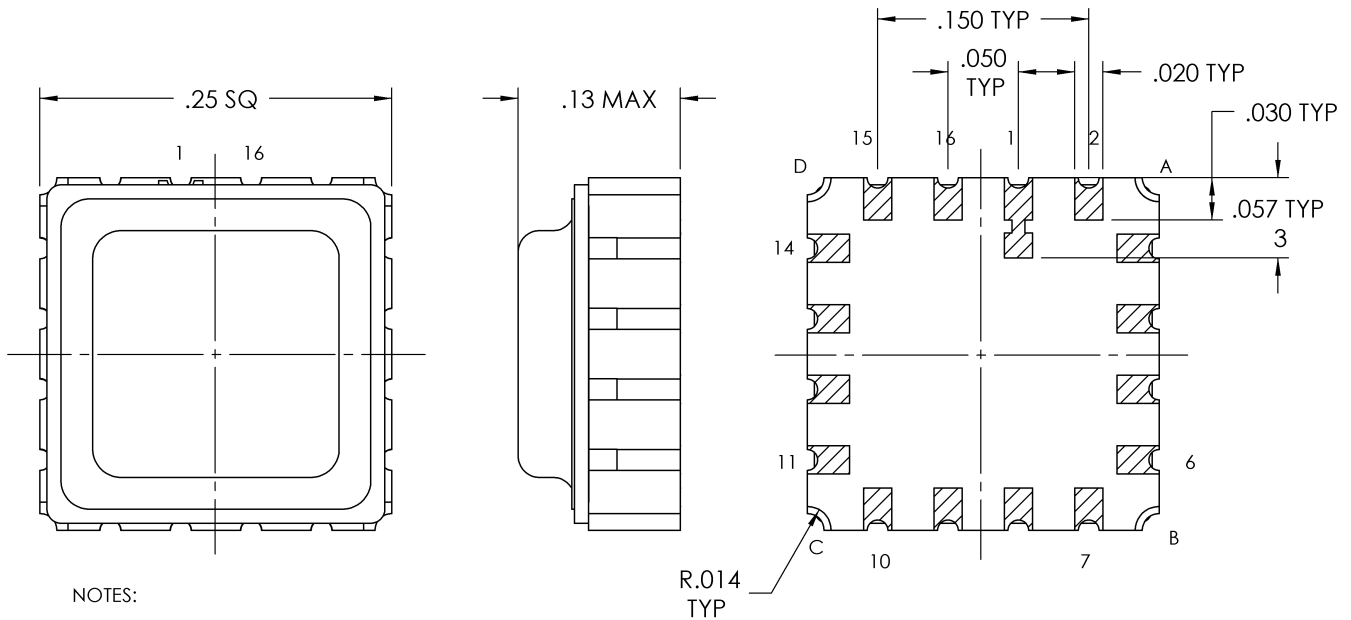
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Electrical Schematic



A, B, C, D IS CONNECTED TO LID

Mechanical Outline



NOTES:

1. CONNECT ALL REDUNDANT PINS TO MEET ELECTRICAL SPECIFICATION.

2. TOLERANCE UNLESS OTHERWISE NOTED
.XX = ±.01
.XXX = ±.005

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PART ORDERING INFORMATION

Part Number	Sensitron Screening Level	Screened In Accordance to:
SDA1007	-	-
SDA1007S	S	MIL-PRF-38534, Class H
SDA1007SS	SS	MIL-PRF-38534, Class K

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